МICROCHIP 25АА040/25LC040/25C040

4K SPITM Bus Serial EEPROM

DEVICE SELECTION TABLE

Part Number	Vcc Range	Max Clock Frequency	Temp Ranges
25AA040	1.8-5.5V	1 MHz	C,I
25LC040	2.5-5.5V	2 MHz	C,I
25C040	4.5-5.5V	3 MHz	C,I,E

FEATURES

- Low power CMOS technology
 - Write current: 3 mA typical
 - Read current: 500 µA typical
 - Standby current: 500 nA typical
- 512 x 8 bit organization
- 16 byte page
- Write cycle time: 5ms max.
- Self-timed ERASE and WRITE cycles
- · Block write protection
 - Protect none, 1/4, 1/2, or all of array
- · Built-in write protection
 - Power on/off data protection circuitry
 - Write enable latch
 - Write protect pin
- · Sequential read
- High reliability
 - Endurance: 1M cycles (guaranteed)
 - Data retention: > 200 years
 - ESD protection: > 4000 V
- 8-pin PDIP, SOIC, and TSSOP packages

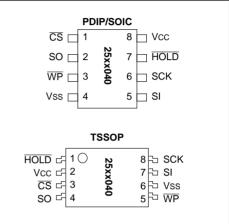
,	Temperature ranges supported:	-	
	 Commercial (Č): 	0°C to +70°C	
	- Industrial (I):	-40°C to +85°C	
	- Automotive (E) (25C040):	-40°C to +125°C	

DESCRIPTION

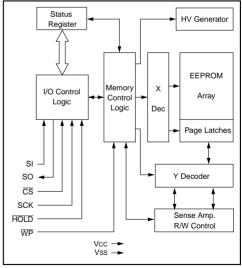
The Microchip Technology Inc. 25A040/25LC040/25C040 ($25xx040^{\circ}$) is a 4K bit serial Electrically Erasable PROM. The memory is accessed via a simple Serial Peripheral Interface (SPI) compatible serial bus. The bus signals required are a clock input (SCK) plus separate data in (SI) and data out (SO) lines. Access to the device is controlled through a chip select (\overline{CS}) input.

Communication to the device can be paused via the hold pin (HOLD). While the device is paused, transitions on its inputs will be ignored, with the exception of chip select, allowing the host to service higher priority interrupts. Also, write operations to the device can be disabled via the write protect pin (\overline{WP}).

PACKAGE TYPES



BLOCK DIAGRAM



*25xx040 is used in this document as a generic part number for the 25AA040/25LC040/25C040 devices. SPI is a trademark of Motorola.

1.0 ELECTRICAL CHARACTERISTICS

1.1 Maximum Ratings*

Vcc	7.0V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc+1.0V
Storage temperature	65°C to 150°C
Ambient temperature under bias	65°C to 125°C
Soldering temperature of leads (10 second	s)+300°C
ESD protection on all pins	4kV

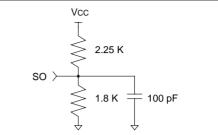
*Notice: Stresses above those listed under 'Maximum ratings' may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability

TABLE 1-1: PIN FUNCTION TABLE

Name	Function	
CS	Chip Select Input	
SO	Serial Data Output	
SI	Serial Data Input	
SCK	Serial Clock Input	
WP	Write Protect Pin	
Vss	Ground	
Vcc	Supply Voltage	
HOLD	Hold Input	

TABLE 1-3: DC CHARACTERISTICS

FIGURE 1-2: AC TEST CIRCUIT



1.2 AC Test Conditions

AC Waveform:

VLO = 0.2V	
VHI = VCC - 0.2V	(Note 1)
VHI = 4.0V	(Note 2)
Timing Measurement Refere	nce Level
Input	0.5 Vcc
Output	0.5 Vcc
Note 1: For VCC \leq 4.0V	
2: For VCC > 4.0V	

All parameters apply over the specified operating ranges unless otherwise noted.	pecified operating ranges Industrial (I): TAMB = -40°C to +85°C Vcc = 1.8V to 5.5V					
Parameter	Symbol	Min	Max	Units	Test Conditions	
	VIH1	2.0	Vcc+1	V	Vcc ≥ 2.7V (Note)	
High level input voltage	VIH2	0.7 Vcc	Vcc+1	V	Vcc< 2.7V (Note)	
	Vi∟1	-0.3	0.8	V	Vcc ≥ 2.7V (Note)	
Low level input voltage	VIL2	-0.3	0.3 Vcc	V	Vcc < 2.7V (Note)	
Low level output voltage	Vol	_	0.4	V	IOL = 2.1 mA	
	Vol	—	0.2	V	IOL = 1.0 mA, VCC < 2.5V	
High level output voltage	Voн	Vcc -0.5	—	V	Юн =-400 μА	
Input leakage current	ILI	-10	10	μA	\overline{CS} = VCC, VIN = VSS TO VCC	
Output leakage current	Ilo	-10	10	μA	CS = Vcc, Vout = Vss to Vcc	
Internal Capacitance (all inputs and outputs)	CINT	—	7	pF	TAMB = 25°C, CLK = 1.0 MHz, VCC = 5.0V (Note)	
Operating Current	ICC Read	_	1 500	mA μA	Vcc = 5.5V; FcLk=3.0 MHz; SO = Open Vcc = 2.5V; FcLk=2.0 MHz; SO = Open	
Operating Current	ICC Write	—	5	mA	VCC= 5.5V	
		_	3	mA	VCC = 2.5V	
Standby Current	Iccs	_	5 2	μΑ μΑ	\overline{CS} = Vcc = 5.5V, Inputs tied to Vcc or Vss \overline{CS} = Vcc = 2.5V, Inputs tied to Vcc or Vss	

Note: This parameter is periodically sampled and not 100% tested.

All parameters apply over the specified operating ranges unless otherwise noted.	Commercial (C): Industrial (I): Automotive (E):	Tamb = -4	°C to +70°C I0°C to +85°C I0°C to +125°	VCC = 1.	8V to 5.5V 8V to 5.5V 5V to 5.5V (25C040 only)
Parameter	Symbol	Min	Max	Units	Test Conditions
Clock Frequency	FCLK	_	3	MHz	$V_{CC} = 4.5V$ to 5.5V
eleok requerey	I OLIX	_	2	MHz	$V_{CC} = 2.5V \text{ to } 4.5V$
		_	1	MHz	Vcc = 1.8V to 2.5V
CS Setup Time	Tcss	100	_	ns	Vcc = 4.5V to 5.5V
		250	_	ns	Vcc = 2.5V to 4.5V
		500	_	ns	Vcc = 1.8V to 2.5V
CS Hold Time	Тсян	150	_	ns	Vcc = 4.5V to 5.5V
		250	_	ns	Vcc = 2.5V to 4.5V
		475	—	ns	Vcc = 1.8V to 2.5V
CS Disable Time	TCSD	500	_	ns	
Data Setup Time	Tsu	30	_	ns	Vcc = 4.5V to 5.5V
		50	_	ns	VCC = 2.5V to $4.5V$
		50	_	ns	Vcc = 1.8V to 2.5V
Data Hold Time	THD	50	_	ns	Vcc = 4.5V to 5.5V
		100	_	ns	Vcc = 2.5V to 4.5V
		100	—	ns	Vcc = 1.8V to 2.5V
CLK Rise Time	TR	_	2	μs	(Note 1)
CLK Fall Time	TF	_	2	μs	(Note 1)
Clock High Time	Тні	150	_	ns	Vcc = 4.5V to 5.5V
		250	_	ns	VCC = 2.5V to $4.5V$
		475	_	ns	Vcc = 1.8V to 2.5V
Clock Low Time	TLO	150	_	ns	Vcc = 4.5V to 5.5V
		250	_	ns	Vcc = 2.5V to 4.5V
		475	—	ns	Vcc = 1.8V to 2.5V
Clock Delay Time	TCLD	50	_	ns	
Clock Enable Time	TCLE	50	_	ns	
Output Valid from	Τv	_	150	ns	Vcc = 4.5V to 5.5V
Clock Low		_	250	ns	$V_{CC} = 2.5V$ to $4.5V$
		_	475	ns	Vcc = 1.8V to 2.5V
Output Hold Time	Тно	0	_	ns	(Note 1)
Output Disable Time	TDIS	_	200	ns	Vcc = 4.5V to 5.5V (Note 1)
	1010	_	250	ns	$V_{CC} = 2.5V \text{ to } 4.5V (Note 1)$
		_	500	ns	Vcc = 1.8V to 2.5V (Note 1)
HOLD Setup Time	Тнѕ	100	_	ns	Vcc = 4.5V to 5.5V
		100	_	ns	VCC = 2.5V to $4.5V$
		200	—	ns	Vcc = 1.8V to 2.5V
HOLD Hold Time	Тнн	100	_	ns	Vcc = 4.5V to 5.5V
		100		ns	VCC = 2.5V to $4.5V$
		200		ns	Vcc = 1.8V to 2.5V
HOLD Low to Output High-Z	Тнz	100	_	ns	Vcc = 4.5V to 5.5V (Note 1)
		150	_	ns	Vcc = 2.5V to 4.5V (Note 1)
		200	—	ns	VCC = 1.8V to 2.5V (Note 1)
HOLD High to Output Valid	THV	100	_	ns	Vcc = 4.5V to 5.5V
		150	-	ns	VCC = 2.5V to 4.5V
		200	—	ns	Vcc = 1.8V to 2.5V
Internal Write Cycle Time	Twc	_	5	ms	
Endurance		1M	_	E/W Cycles	(Note 2)

TABLE 1-4: AC CHARACTERISTICS

Note 1: This parameter is periodically sampled and not 100% tested.

2: This parameter is not tested but guaranteed by characterization. For endurance estimates in a specific application, please consult the Total Endurance Model which can be obtained on our website.

25AA040/25LC040/25C040

FIGURE 1-5: HOLD TIMING

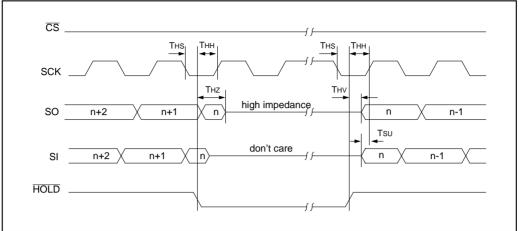
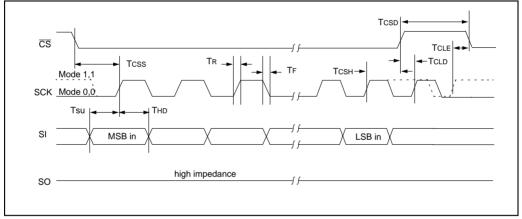
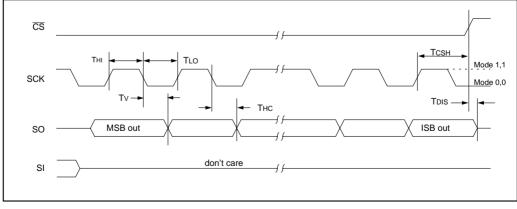


FIGURE 1-6: SERIAL INPUT TIMING







2.0 PIN DESCRIPTIONS

2.1 Chip Select (CS)

A low level on this pin selects the device. A high level deselects the device and forces it into standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of the $\overline{\text{CS}}$ input signal. If $\overline{\text{CS}}$ is brought high during a program cycle, the device will go in standby mode as soon as the programming cycle is complete. As soon as the device is deselected, SO goes to the high impedance state, allowing multiple parts to share the same SPI bus. A low to high transition on $\overline{\text{CS}}$ after a valid write sequence initiates an internal write cycle. After power-up, a low level on $\overline{\text{CS}}$ is required prior to any sequence being initiated.

2.2 Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses, and data. Data is latched on the rising edge of the serial clock.

2.3 Serial Output (SO)

The SO pin is used to transfer data out of the 25xx040. During a read cycle, data is shifted out on this pin after the falling edge of the serial clock.

2.4 Serial Clock (SCK)

The SCK is used to synchronize the communication between a master and the 25xx040. Instructions, addresses, or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

2.5 <u>Write Protect (WP)</u>

This pin is a hardware write protect input pin. When \overline{WP} is low, all writes to the array or status register are disabled, but any other operation functions normally. When \overline{WP} is high, all functions, including non-volatile writes operate normally. \overline{WP} going low at any time will reset the write enable latch and inhibit programming, except when an internal write has already begun. If an internal write cycle has already begun, \overline{WP} going low will have no effect on the write. See Table 3-7 for Write Protect Functionality Matrix.

2.6 Hold (HOLD)

The HOLD pin is used to suspend transmission to the 25xx040 while in the middle of a serial sequence without having to re-transmit the entire sequence over at a later time. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the HOLD pin may be pulled low to pause further serial communication without resetting the serial sequence. The HOLD pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high to low transition. The 25xx040 must remain selected during this sequence. The SI. SCK, and SO pins are in a high impedance state during the time the part is paused and transitions on these pins will be ignored. To resume serial communication. HOLD must be brought high while the SCK pin is low, otherwise serial communication will not resume. Lowering the HOLD line at any time will tri-state the SO line.

3.0 FUNCTIONAL DESCRIPTION

3.1 PRINCIPLES OF OPERATION

The 25xx040 is a 512 byte Serial EEPROM designed to interface directly with the Serial Peripheral Interface (SPI) port of many of today's popular microcontroller families, including Microchip's PIC16C6X/7X microcontrollers. It may also interface with microcontrollers that do not have a built-in SPI port by using discrete I/O lines programmed properly with the software.

The 25xx040 contains an 8-bit instruction register. The part is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The $\overline{\text{CS}}$ pin must be low and the $\overline{\text{HOLD}}$ pin must be high for the entire operation. The $\overline{\text{WP}}$ pin must be held high to allow writing to the memory array.

Table 3-1 contains a list of the possible instruction bytes and format for device operation. The most significant address bit (A8) is located in the instruction byte. All instructions, addresses, and data are transferred MSB first, LSB last.

Data is sampled on the first rising edge of SCK after $\overline{\text{CS}}$ goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the $\overline{\text{HOLD}}$ input and place the 25xx040 in 'HOLD' mode. After releasing the $\overline{\text{HOLD}}$ pin, operation will resume from the point when the $\overline{\text{HOLD}}$ was asserted.

3.2 Read Sequence

The part is selected by pulling $\overline{\text{CS}}$ low. The 8-bit read instruction with the A8 address bit is transmitted to the 25xx040 followed by the lower 8-bit address (A7 through A0). After the correct read instruction and address are sent, the data stored in the memory at the selected address is shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal address pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (01FFh), the address counter rolls over to address 0000h allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the $\overline{\text{CS}}$ pin (Figure 3-2).

3.3 Write Sequence

Prior to any attempt to write data to the 25xx040, the write enable latch must be set by issuing the WREN instruction (Figure 3-5). This is done by setting \overline{CS} low and then clocking out the proper instruction into the 25xx040. After all eight bits of the instruction are transmitted, the \overline{CS} must be brought high to set the write enable latch. If the write operation is initiated immediately after the WREN instruction without \overline{CS} being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

Once the write enable latch is set, the user may proceed by setting the \overline{CS} low, issuing a write instruction, followed by the address, and then the data to be written. Keep in mind that the most significant address bit (A8) is included in the instruction byte. Up to 16 bytes of data can be sent to the 25xx040 before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page. A page address begins with XXXX 0000 and ends with XXXX 1111. If the internal address counter reaches XXXX 1111 and the clock continues, the counter will roll back to the first address of the page and overwrite any data in the page that may have been written.

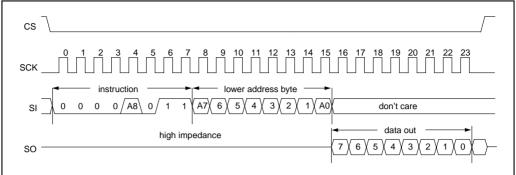
For the data to be actually written to the array, the \overline{CS} must be brought high after the least significant bit (D0) of the nth data byte has been clocked in. If \overline{CS} is brought high at any other time, the write operation will not be completed. Refer to Figure 3-3 and Figure 3-4 for more detailed illustrations on the byte write sequence and the page write sequence respectively. While the write is in progress, the status register may be read to check the status of the WIP, WEL, BP1, and BP0 bits (Figure 3-8). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

Instruction Name	Instruction Format	Description
READ	0000 A ₈ 011	Read data from memory array beginning at selected address
WRITE	0000 A ₈ 010	Write data to memory array beginning at selected address
WRDI	0000 0100	Reset the write enable latch (disable write operations)
WREN	0000 0110	Set the write enable latch (enable write operations)
RDSR	0000 0101	Read status register
WRSR	0000 0001	Write status register

TABLE 3-1: INSTRUCTION SET

Note: A_8 is the 9th address bit necessary to fully address 512 bytes.

FIGURE 3-2: READ SEQUENCE





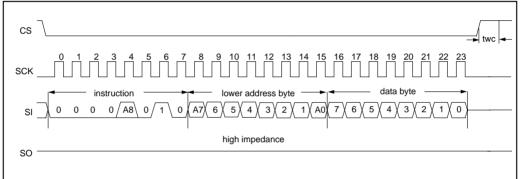
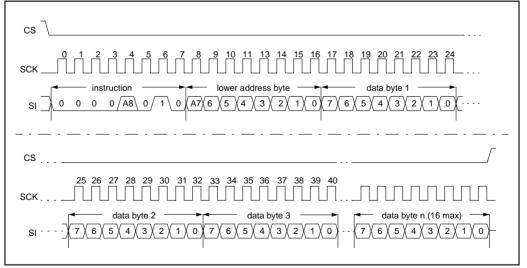


FIGURE 3-4: PAGE WRITE SEQUENCE



3.4 <u>Write Enable (WREN) and Write</u> Disable (WRDI)

The 25xx040 contains a write enable latch. See Table 3-10 for the Write Protect Functionality Matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch, and the WRDI will reset the latch. The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed
- $\overline{\mathsf{WP}}$ line is low

FIGURE 3-5: WRITE ENABLE SEQUENCE

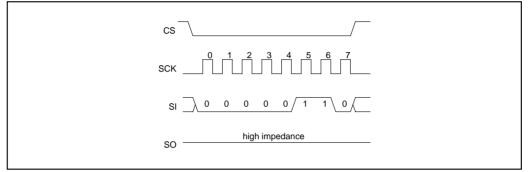
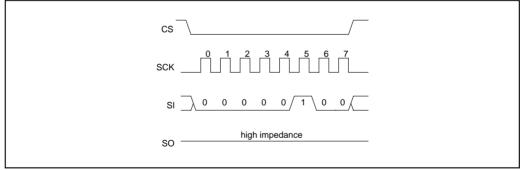


FIGURE 3-6: WRITE DISABLE SEQUENCE



3.5 Read Status Register (RDSR)

The RDSR instruction provides access to the status register. The status register may be read at any time, even during a write cycle. The status register is formatted as follows:

7	6	5	4	3	2	1	0
Х	Х	Х	Х	BP1	BP0	WEL	WIP

The **Write-In-Process (WIP)** bit indicates whether the 25xx040 is busy with a write operation. When set to a '1' a write is in progress, when set to a '0' no write is in progress. This bit is read only.

The **Write Enable Latch (WEL)** bit indicates the status of the write enable latch. When set to a '1' the latch allows writes to the array, when set to a '0' the latch prohibits writes to the array. The state of this bit can always be updated via the WREN or WRDI commands regardless of the state of write protection on the status register. This bit is read only.

The **Block Protection (BP0 and BP1)** bits indicate which blocks are currently write protected. These bits are set by the user issuing the WRSR instruction. These bits are non-volatile.

See Figure 3-8 for RDSR timing sequence

time, four levels of protection for the array by writing to the

3.6

appropriate bits in the status register. The array is divided up into four segments. The user has the ability to write protect none, one, two, or all four of the segments of the array. The partitioning is controlled as illustrated in Table 3-7.

Write Status Register(WRSR)

The WRSR instruction allows the user to select one of

See Figur	e 3-9	for WRSR	timing	sequence
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BP1	BP1 BP0 Array Ad Write Pr	
0	0	none
0	1	upper 1/4 (0180h - 01FFh)
1	0	upper 1/2 (0100h - 01FFh)
1	1	all (0000h - 01FFh)

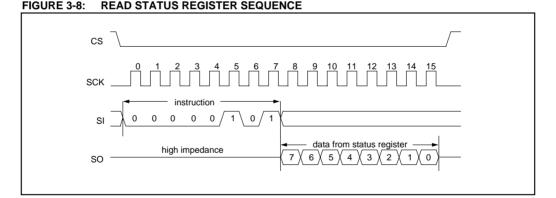
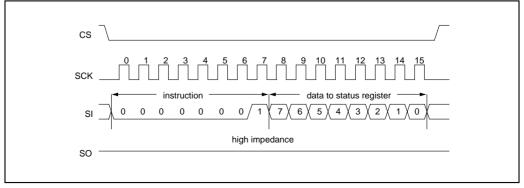


FIGURE 3-9: WRITE STATUS REGISTER SEQUENCE



25AA040/25LC040/25C040

3.7 Data Protection

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up.
- A write enable instruction must be issued to set the write enable latch.
- After a byte write, page write, or status register write, the write enable latch is reset.
- CS must be set high after the proper number of clock cycles to start an internal write cycle.
- Access to the array during an internal write cycle is ignored and programming is continued.
- The write enable latch is reset when the WP pin is low.

3.8 Power On State

The 25xx040 powers on in the following state:

- The device is in low power standby mode $(\overline{CS} = 1)$.
- The write enable latch is reset.
- SO is in high impedance state.
- A low level on \overline{CS} is required to enter active state.

TABLE 3-10: WRITE PROTECT FUNCTIONALITY MATRIX

WP	WEL	Protected Blocks	Unprotected Blocks	Status Register	
Low	Х	Protected	Protected	Protected	
High	0	Protected	Protected	Protected	
High	1	Protected	Writable	Writable	

25AA040/25LC040/25C040 PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

25xx040 — _ /P_							
		— TT I		Р	= Plastic DIP (300 mil Body), 8-lead		
			Package:	SN	= Plastic SOIC (150 mil Body), 8-lead		
				ST	= TSSOP, 8-lead		
			Temperature Range:				
					$= 0^{\circ}C$ to $+70^{\circ}C$		
				-	= −40°C to +85°C		
				E	= −40°C to +125°C		
				25AA040	4096 bit 1.8V SPI Serial EEPROM		
				25AA040T	4096 bit 1.8V SPI Serial EEPROM Tape and Reel		
				25AA040X	4096 bit 1.8V SPI Serial EEPROM		
					in alternate pinout (ST only)		
				25AA040XT	4096 bit 1.8V SPI Serial EEPROM		
					in alternate pinout Tape and Reel (ST only)		
				25LC040	4096 bit 2.5V SPI Serial EEPROM		
				25LC040T	4096 bit 2.5V SPI Serial EEPROM Tape and Reel		
			Devices:	25LC040X	4096 bit 2.5V SPI Serial EEPROM		
					in alternate pinout (ST only)		
				25LC040XT	4096 bit 2.5V SPI Serial EEPROM		
					in alternate pinout Tape and Reel (ST only)		
				25C040			
				25C040T	4096 bit 5.0V SPI Serial EEPROM Tape and Reel		
				25C040X			
					in alternate pinout (ST only)		
				25C040XT			
					in alternate pinout Tape and Reel (ST only)		

Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Corporate Literature Center U.S. FAX: (602) 786-7277
- 3. The Microchip Worldwide Web Site (www.microchip.com)



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Microchip Technology Inc. 150 Motor Parkway, Suite 202 Hauppauge, NY 11788 Tel: 516-273-5305 Fax: 516-273-5335

San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

AMERICAS (continued)

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Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea Tel: 82-2-554-7200 Fax: 82-2-558-5934

Shanghai

Microchip Technology RM 406 Shanghai Golden Bridge Bldg. 2077 Yan'an Road West, Hong Qiao District Shanghai, PRC 200335 Tel: 86-21-6275-5700 Fax: 86 21-6275-5060

ASIA/PACIFIC (continued)

Singapore

Microchip Technology Singapore Pte Ltd. 200 Middle Road #07-02 Prime Centre Singapore 188980 Tel: 65-334-8870 Fax: 65-334-8850

Taiwan, R.O.C

Microchip Technology Taiwan 10F-1C 207 Tung Hua North Road Taipei, Taiwan, ROC Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

EUROPE

United Kingdom

Arizona Microchip Technology Ltd. 505 Eskdale Road Winnersh Triangle Wokingham Berkshire, England RG41 5TU Tel: 44-1189-21-5858 Fax: 44-1189-21-5835 Franco

Arizona Microchip Technology SARL Zone Industrielle de la Bonde 2 Rue du Buisson aux Fraises 91300 Massy, France Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany

Arizona Microchip Technology GmbH Gustav-Heinemann-Ring 125 D-81739 Müchen, Germany Tel: 49-89-627-144 0 Fax: 49-89-627-144-44

Italv

Arizona Microchip Technology SRL Centro Direzionale Colleoni Palazzo Taurus 1 V. Le Colleoni 1 20041 Agrate Brianza Milan, Italy Tel: 39-39-6899939 Fax: 39-39-6899883

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